

SQ4153EY-T1_BE3 Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	SQ4153EY-T1_BE3-DG
Manufacturer	Vishay Siliconix
Manufacturer Product Number	SQ4153EY-T1_BE3
Description	MOSFET P-CHANNEL 12V 25A 8SOIC
Detailed Description	P-Channel 12 V 25A (Tc) 7.1W (Tc) Surface Mount 8 -SOIC

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

er: Inix us: tal Oxide) ntinuous Drain (Id) @ 25°C:
us: tal Oxide)
tal Oxide)
tal Oxide)
tal Oxide)
ntinuous Drain (Id) @ 25°C:
x) @ Id, Vgs:
@ 14A, 4.5V
: (Qg) (Max) @ Vgs:
5 V
itance (Ciss) (Max) @ Vds:
6 V
pation (Max):
pe:
int
ase:
4", 3.90mm Width)

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
ECCN:	HTSUS:
EAR99	8541.29.0095



www.vishay.com

SQ4153EY

Vishay Siliconix

Automotive P-Channel 12 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	-12			
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = -4.5 V	0.00832			
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = -2.5 V	0.01000			
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = -1.8 V	0.01430			
I _D (A)	-25			
Configuration	Single			

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



FREE

P-Channel MOSFET

ORDERING INFORMATION			
Package	SO-8		
Lead (Pb)-free and halogen-free	SQ4153EY (for detailed order number please see <u>www.vishay.com/doc?79771</u>)		

ABSOLUTE MAXIMUM RATING	\mathbf{S} ($\mathbf{I}_{\mathbf{C}} = 25$ °C, unless	otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	-12	V
Gate-source voltage		V _{GS}	± 8	v
Continuous drain current ^a	T _C = 25 °C	I	-25	
Continuous drain current "	T _C = 125 °C	ID	-14	
Continuous source current (diode conduction) ^a		I _S	-6.5	А
Pulsed drain current ^b		I _{DM}	-100	
Single pulse avalanche current		I _{AS}	-19	
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	18	mJ
Maximum maximum disain atism b	T _C = 25 °C	PD	7.1	W
Maximum power dissipation ^b	T _C = 125 °C	۳D	2.3	vv
Operating junction and storage temperature	range	T _J , T _{stq}	-55 to +175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB Mount ^c	R _{thJA}	85	°C/W	
Junction-to-foot (drain)		R _{thJF}	21	C/W	

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

S21-0375-Rev. C, 23-Apr-2021

1

Document Number: 66897



Vishay Siliconix

SPECIFICATIONS ($T_c = 25 \circ C$	C, unless othe	rwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = -250 μA	-12	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V_{GS} , I_D = -250 μ A	-0.4	-0.6	-0.9	v
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -12 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = -12 V, T _J = 125 °C	-	-	-50	μA
		$V_{GS} = 0 V$	V _{DS} = -12 V, T _J = 175 °C	-	-	-150	
On-state drain current ^a	I _{D(on)}	$V_{GS} = -4.5 V$	$V_{DS} \ge -5 V$	-30	-	-	А
		$V_{GS} = -4.5 V$	I _D = -14 A	-	0.00510	0.00832	
		$V_{GS} = -4.5 V$	I _D = -14 A, T _J = 125 °C	-	-	0.00900	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V	I _D = -14 A, T _J = 175 °C	-	-	0.01100	Ω
		V _{GS} = -2.5 V	I _D = -13 A	-	0.00650	0.01000	
		V _{GS} = -1.8 V	I _D = -12 A	-	0.00940	0.01430	
Forward transconductance ^a	g _{fs}	V _{DS} =	-6 V, I _D = -10.5 A	-	54	-	S
Dynamic ^b					•		•
Input capacitance	C _{iss}			-	7500	11 000	
Output capacitance	C _{oss}	V _{GS} = 0 V V _{DS} = -6 V, f = 1 MHz		-	2800	4200	pF
Reverse transfer capacitance	C _{rss}			-	2400	3600	1
Total gate charge ^c	Qg			-	101	151	
Gate-source charge ^c	Q _{gs}	V _{GS} = -4.5 V	$V_{DS} = -6 \text{ V}, \text{ I}_{D} = -10.5 \text{ A}$	-	15	-	nC
Gate-drain charge ^c	Q _{gd}			-	45	-	1
Gate resistance	Rg	f = 1 MHz		1.1	2.2	3.2	Ω
Turn-on delay time ^c	t _{d(on)}			-	31	42	
Rise time ^c	tr	V_{DD} = -6 V, R _L = 15 Ω I _D \cong -10.5 A, V _{GEN} = -4.5 V, R _g = 6 Ω		-	168	224	1
Turn-off delay time ^c	t _{d(off)}			-	310	412	ns
Fall time ^c	t _f			-	283	376	1
Source-Drain Diode Ratings and Cha	racteristics ^b						
Pulsed current ^a	I _{SM}			-	-	-100	A
Forward voltage	V _{SD}	I _F =	-10.5 A, V _{GS} = 0	-	-0.8	-1.2	V

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

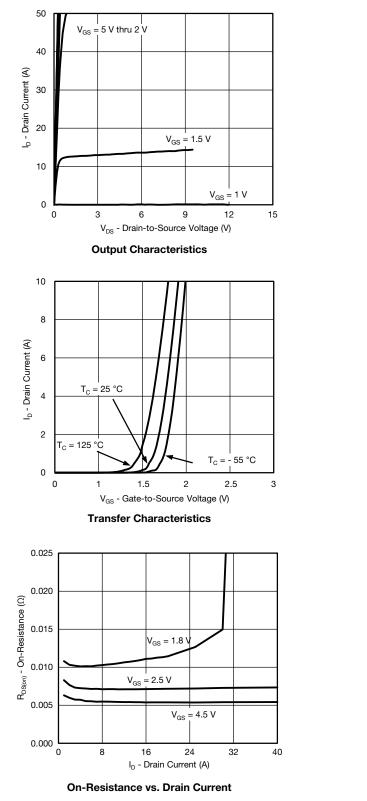
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

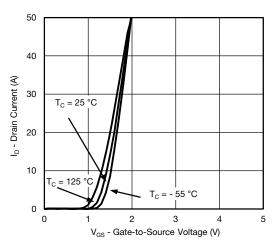
2



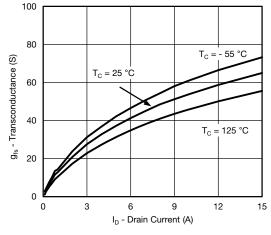
Vishay Siliconix

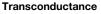
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

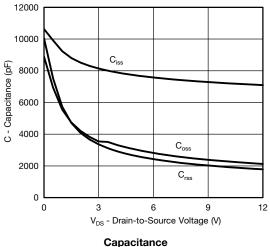




Transfer Characteristics







S21-0375-Rev. C, 23-Apr-2021

3

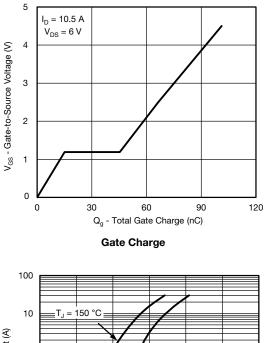
Document Number: 66897

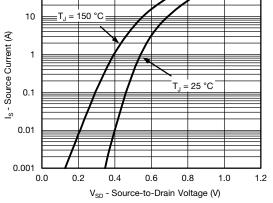
For technical questions, contact: automostechsupport@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



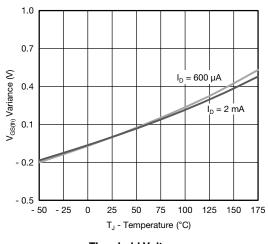
Vishay Siliconix

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

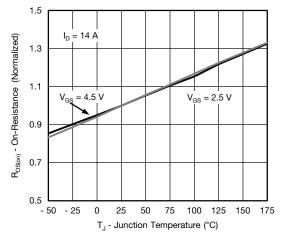




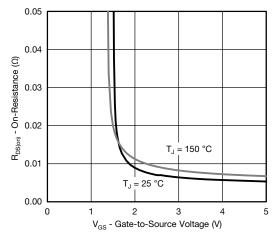
Source Drain Diode Forward Voltage



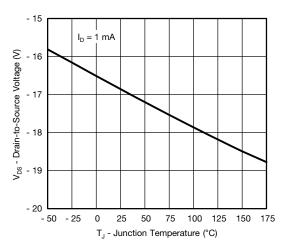
Threshold Voltage



On-Resistance vs. Junction Temperature







Breakdown Voltage vs. Junction Temperature

S21-0375-Rev. C, 23-Apr-2021

4

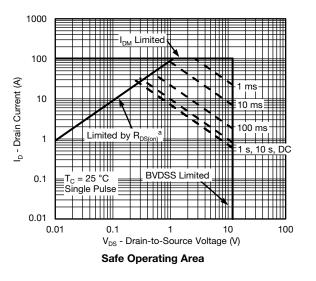
Document Number: 66897

For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



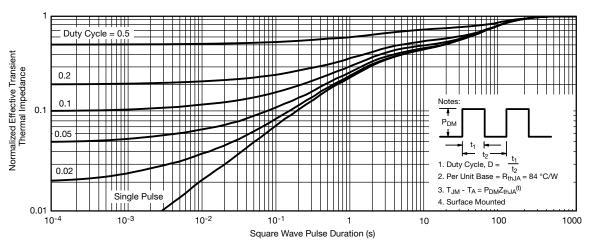
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

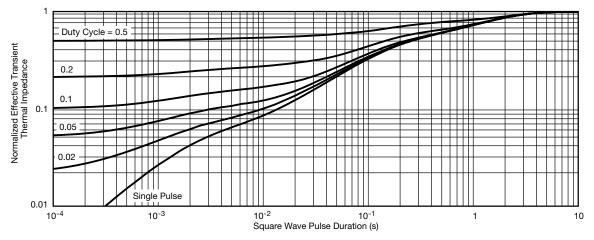


Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?66897.

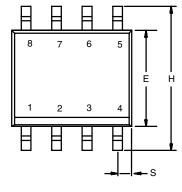
S21-0375-Rev. C, 23-Apr-2021	6	Document Number: 66897
For tec	hnical questions, contact: <u>automostechsupport@vishay.con</u>	<u>n</u>
	HANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED	
ARE SUBJECT TO	SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com	<u>1/doc?91000</u>

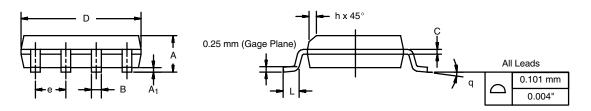


Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





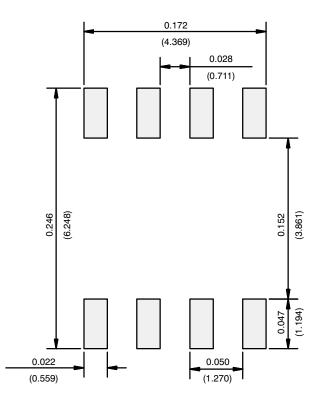
	MILLIM	IETERS	INC	HES
DIM	Min	Мах	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
е	e 1.27 BSC		0.050 BSC	
н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-0652 DWG: 5498	ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498			

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1



OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

	<section-header></section-header>		
Image: State	Here and the second sec	Hand and a set of the	





Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.